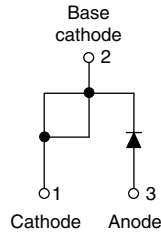


## Ultrafast Rectifier, 15 A FRED Pt®


**TO-220AC**


### FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified for industrial level


**RoHS**  
COMPLIANT

### DESCRIPTION/APPLICATIONS

VS-MUR1520PbF is the state of the art ultrafast recovery rectifier specifically designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### PRODUCT SUMMARY

Package	TO-220AC
$I_{F(AV)}$	15 A
$V_R$	200 V
$V_F$ at $I_F$	1.05 V
$t_{rr}$ typ.	See Recovery table
$T_J$ max.	175 °C
Diode variation	Single die

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Peak repetitive reverse voltage	$V_{RRM}$		200	V
Average rectified forward current	$I_{F(AV)}$	Total device, rated $V_R$ , $T_C = 150$ °C	15	A
Non-repetitive peak surge current	$I_{FSM}$		200	
Peak repetitive forward current	$I_{FM}$	Rated $V_R$ , square wave, 20 kHz, $T_C = 150$ °C	30	
Operating junction and storage temperatures	$T_J, T_{Stg}$		- 65 to 175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25$ °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100$ $\mu$ A	200	-	-	V
Forward voltage	$V_F$	$I_F = 15$ A	-	-	1.05	
		$I_F = 15$ A, $T_J = 150$ °C	-	-	0.85	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	10	$\mu$ A
		$T_J = 150$ °C, $V_R = V_R$ rated	-	-	500	
Junction capacitance	$C_T$	$V_R = 200$ V	-	55	-	pF
Series inductance	$L_S$	Measured lead to lead 5 mm from package body	-	8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 1.0 A, di <sub>F</sub> /dt = 50 A/μs, V <sub>R</sub> = 30 V		-	-	35	ns
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A di <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 160 V	-	22	-	
		T <sub>J</sub> = 125 °C		-	39	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A di <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 160 V	-	1.6	-	A
		T <sub>J</sub> = 125 °C		-	4.1	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A di <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 160 V	-	19	-	nC
		T <sub>J</sub> = 125 °C		-	90	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>			- 65	-	175	°C
Thermal resistance, junction to case	R <sub>thJC</sub>			-	-	1.5	°C/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>			-	-	50	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased		-	0.5	-	
Weight				-	2.0	-	g
				-	0.07	-	oz.
Mounting torque				6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220AC		MUR1520			

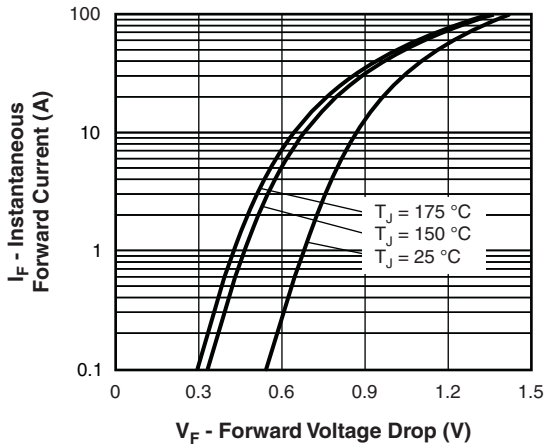


Fig. 1 - Typical Forward Voltage Drop Characteristics

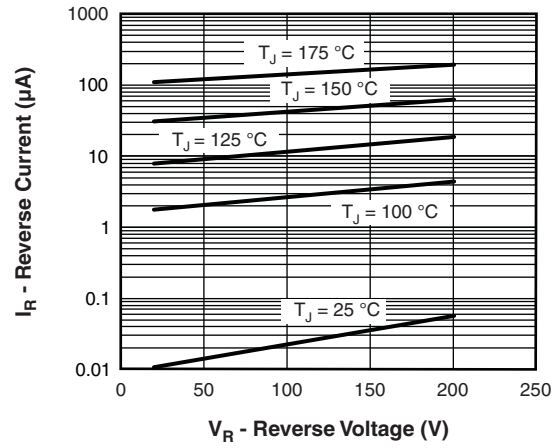


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

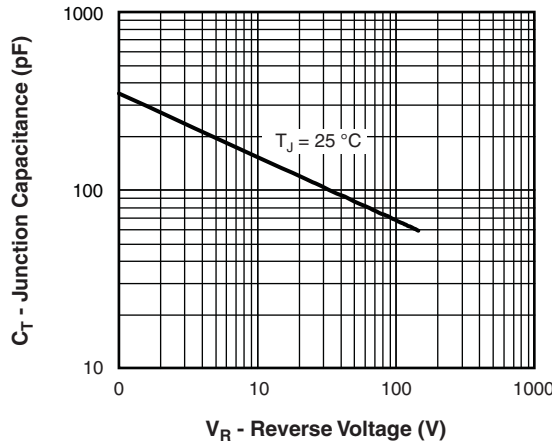


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

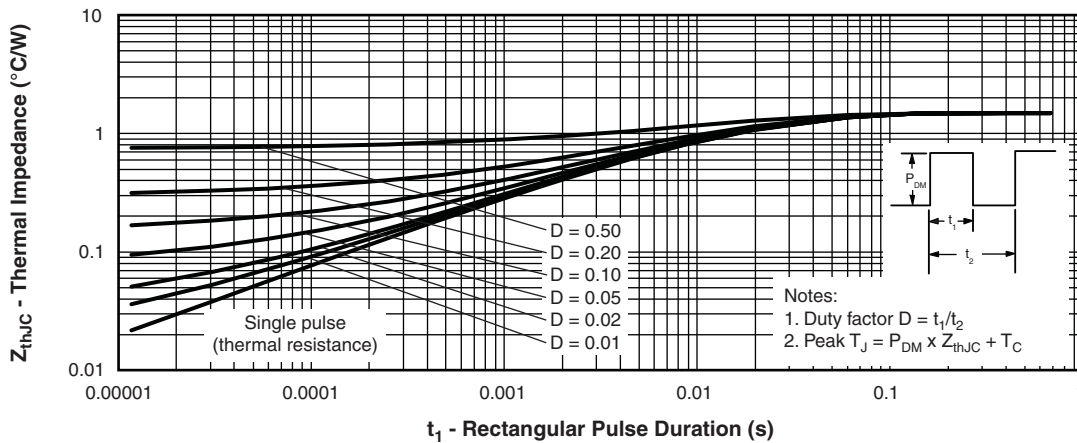


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

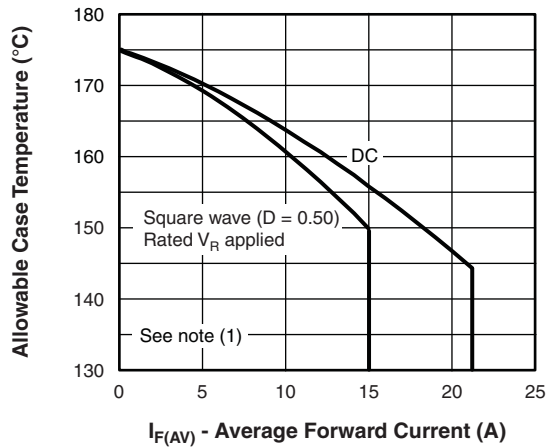


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

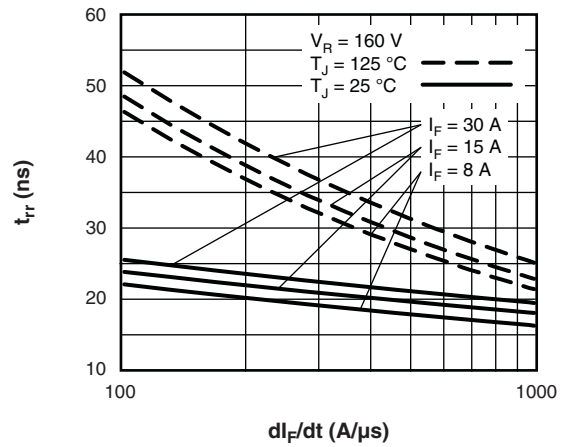


Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$

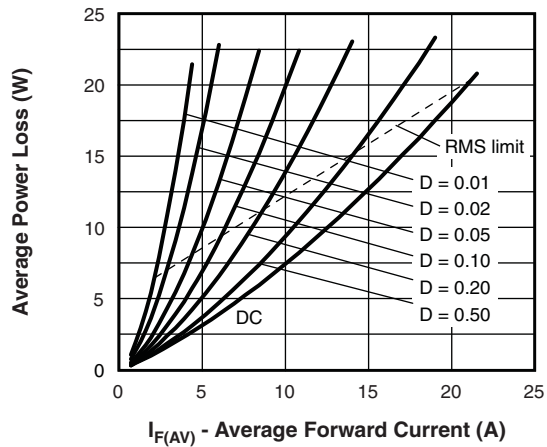


Fig. 6 - Forward Power Loss Characteristics

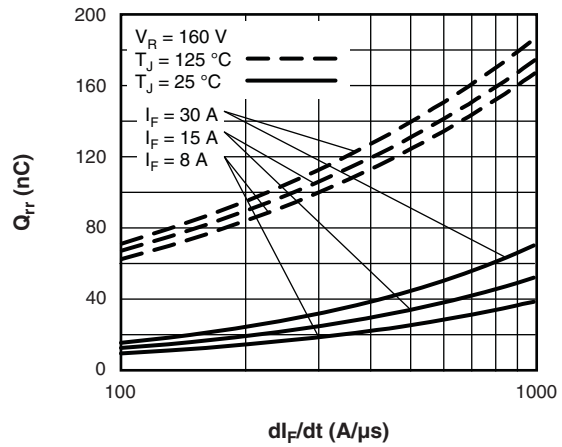


Fig. 8 - Typical Stored Charge vs.  $di_F/dt$

**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$ ;  
 $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{d_{REV}}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$

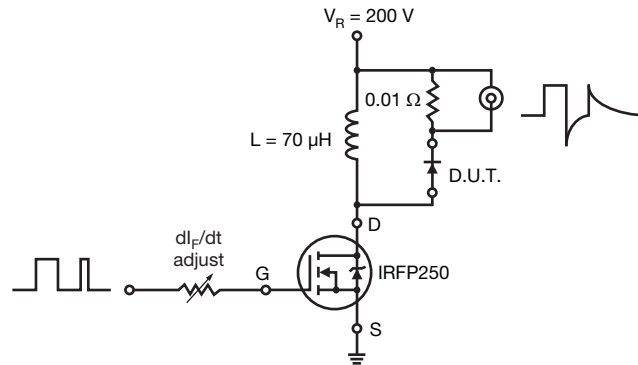


Fig. 9 - Reverse Recovery Parameter Test Circuit

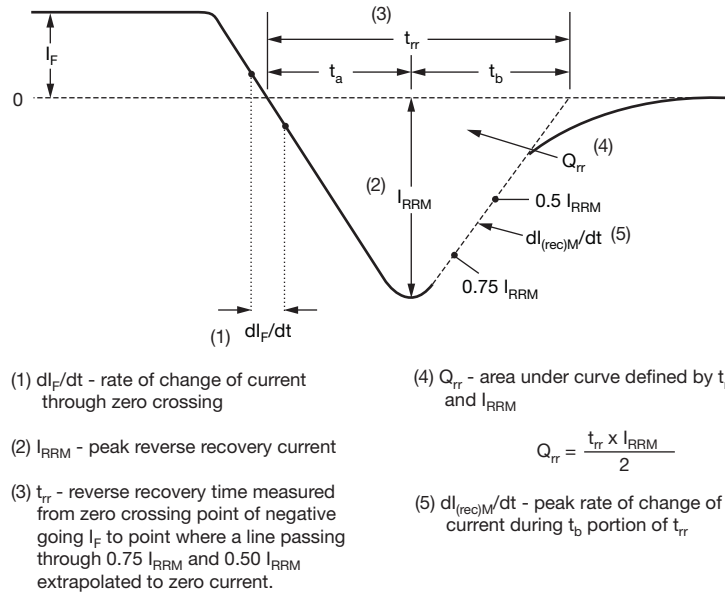


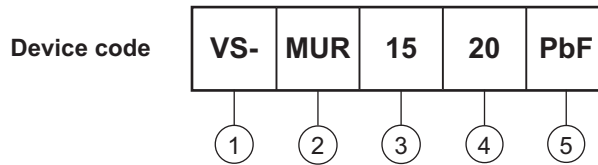
Fig. 10 - Reverse Recovery Waveform and Definitions

# VS-MUR1520PbF

Vishay Semiconductors Ultrafast Rectifier, 15 A FRED Pt®



## ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Ultrafast MUR series
- 3** - Current rating (15 = 15 A)
- 4** - Voltage rating (20 = 200 V)
- 5** - PbF = Lead (Pb)-free

Tube standard pack quantity: 50 pieces

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95221">www.vishay.com/doc?95221</a>
Part marking information	<a href="http://www.vishay.com/doc?95224">www.vishay.com/doc?95224</a>
SPICE model	<a href="http://www.vishay.com/doc?95271">www.vishay.com/doc?95271</a>

## TO-220AC

**DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		e	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
c	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	Ø P	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° to 93°		90° to 93°		
E	10.11	10.51	0.398	0.414	3, 6						

**Notes**

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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